

# Yihui He

## List of Publications by Year in descending order

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61  
papers

3,029  
citations

257450

24  
h-index

168389

53  
g-index

63  
all docs

63  
docs citations

63  
times ranked

2858  
citing authors

#	ARTICLE	IF	CITATIONS
1	Study of Annihilation Photon Pair Coincidence Time Resolution Using Prompt Photon Emissions in New Perovskite Bulk Crystals. IEEE Transactions on Radiation and Plasma Medical Sciences, 2022, 6, 804-810.	3.7	2
2	Sensitivity and Detection Limit of Spectroscopic-Grade Perovskite CsPbBr <sub>3</sub> Crystal for Hard X-ray Detection. Advanced Functional Materials, 2022, 32, .	14.9	32
3	Detecting ionizing radiation using halide perovskite semiconductors processed through solution and alternative methods. Nature Photonics, 2022, 16, 14-26.	31.4	122
4	CsPbBr <sub>3</sub> perovskite detectors with 1.4% energy resolution for high-energy $\hat{\Gamma}^3$ -rays. Nature Photonics, 2021, 15, 36-42.	31.4	210
5	Enhanced Photocurrent of All-Inorganic Two-Dimensional Perovskite Cs <sub>2</sub> PbI <sub>2</sub> Cl <sub>2</sub> via Pressure-Regulated Excitonic Features. Journal of the American Chemical Society, 2021, 143, 2545-2551.	13.7	79
6	Demonstration of Energy-Resolved $\hat{\Gamma}^3$ -Ray Detection at Room Temperature by the CsPbCl <sub>3</sub> Perovskite Semiconductor. Journal of the American Chemical Society, 2021, 143, 2068-2077.	13.7	62
7	Triple-Cation and Mixed-Halide Perovskite Single Crystal for High-Performance X-ray Imaging. Advanced Materials, 2021, 33, e2006010.	21.0	163
8	Amorphous to Crystal Phase Change Memory Effect with Two-Fold Bandgap Difference in Semiconducting K <sub>2</sub> Bi <sub>8</sub> Se <sub>13</sub> . Journal of the American Chemical Society, 2021, 143, 6221-6228.	13.7	9
9	Excitons in CsPbBr <sub>3</sub> Halide Perovskite. Journal of Physical Chemistry Letters, 2021, 12, 9301-9307.	4.6	8
10	Nucleation-controlled growth of superior lead-free perovskite Cs <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub> single-crystals for high-performance X-ray detection. Nature Communications, 2020, 11, 2304.	12.8	286
11	Inch-Size OD-Structured Lead-Free Perovskite Single Crystals for Highly Sensitive Stable X-Ray Imaging. Matter, 2020, 3, 180-196.	10.0	202
12	Three-Dimensional Lead Iodide Perovskitoid Hybrids with High X-ray Photoresponse. Journal of the American Chemical Society, 2020, 142, 6625-6637.	13.7	82
13	Direct thermal neutron detection by the 2D semiconductor 6LiInP <sub>2</sub> Se <sub>6</sub> . Nature, 2020, 577, 346-349.	27.8	59
14	Thermoplastic Membranes Incorporating Semiconductive Metal-Organic Frameworks: An Advance on Flexible X-ray Detectors. Angewandte Chemie, 2020, 132, 11954-11958.	2.0	46
15	Thermoplastic Membranes Incorporating Semiconductive Metal-Organic Frameworks: An Advance on Flexible X-ray Detectors. Angewandte Chemie - International Edition, 2020, 59, 11856-11860.	13.8	60
16	Organic Cation Alloying on Intralayer A and Interlayer A <sup>TM</sup> sites in 2D Hybrid Dion-Jacobson Lead Bromide Perovskites (A <sup>TM</sup> )(A)Pb <sub>2</sub> Br <sub>7</sub> . Journal of the American Chemical Society, 2020, 142, 8342-8351.	13.7	64
17	Monte Carlo simulation of transport properties in wide gap Hg <sub>3</sub> Se <sub>2</sub> I <sub>2</sub> . Semiconductor Science and Technology, 2019, 34, 115003.	2.0	1
18	Antiferromagnetic Semiconductor BaFMn <sub>0.5</sub> Te with Unique Mn Ordering and Red Photoluminescence. Journal of the American Chemical Society, 2019, 141, 17421-17430.	13.7	10

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19	Ultrafast correlated charge and lattice motion in a hybrid metal halide perovskite. <i>Science Advances</i> , 2019, 5, eaaw5558.	10.3	66
20	Purification and Improved Nuclear Radiation Detection of $\text{Tl}_6\text{Si}_4$ Semiconductor. <i>Crystal Growth and Design</i> , 2019, 19, 4738-4744.	3.0	4
21	Controlling the Vapor Transport Crystal Growth of $\text{Hg}_3\text{Se}_2\text{I}_2$ Hard Radiation Detector Using Organic Polymer. <i>Crystal Growth and Design</i> , 2019, 19, 2074-2080.	3.0	7
22	Uniaxial Expansion of the 2D Ruddlesden-Popper Perovskite Family for Improved Environmental Stability. <i>Journal of the American Chemical Society</i> , 2019, 141, 5518-5534.	13.7	193
23	Study of the Coincidence Time Resolution of New Perovskite Bulk Crystals. , 2019, , .		3
24	Carrier recombination mechanism in $\text{CsPbBr}_3$ revealed by time-resolved photoluminescence spectroscopy. <i>Physical Review B</i> , 2019, 100, .	3.2	14
25	Coherent charge-phonon correlations and exciton dynamics in orthorhombic $\text{CH}_3\text{NH}_3\text{PbI}_3$ measured by ultrafast multi-THz spectroscopy. <i>Journal of Chemical Physics</i> , 2019, 151, 214201.	3.0	6
26	Zero-Dimensional $\text{Cs}_2\text{Te}_6$ Perovskite: Solution-Processed Thick Films with High X-ray Sensitivity. <i>ACS Photonics</i> , 2019, 6, 196-203.	6.6	70
27	Noise sources and their limitations on the performance of compound semiconductor hard radiation detectors. <i>Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment</i> , 2019, 916, 133-140.	1.6	4
28	Perovskite $\text{CsPbBr}_3$ single crystal detector for alpha-particle spectroscopy. <i>Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment</i> , 2019, 922, 217-221.	1.6	83
29	High spectral resolution of gamma-rays at room temperature by perovskite $\text{CsPbBr}_3$ single crystals. <i>Nature Communications</i> , 2018, 9, 1609.	12.8	381
30	Stoichiometric Effects on the Photoelectric Properties of $\text{LiInSe}_2$ Crystals for Neutron Detection. <i>Crystal Growth and Design</i> , 2018, 18, 2864-2870.	3.0	16
31	An Effective Purification Process for the Nuclear Radiation Detector $\text{Tl}_6\text{Se}_4$ . <i>Crystal Growth and Design</i> , 2018, 18, 3484-3493.	3.0	9
32	$\text{Cu}_2\text{I}_2\text{Se}_6$ : A Metal-Inorganic Framework Wide-Bandgap Semiconductor for Photon Detection at Room Temperature. <i>Journal of the American Chemical Society</i> , 2018, 140, 1894-1899.	13.7	19
33	Role of Stoichiometry in the Growth of Large $\text{Pb}_2\text{P}_2\text{Se}_6$ Crystals for Nuclear Radiation Detection. <i>ACS Photonics</i> , 2018, 5, 566-573.	6.6	15
34	Abrupt Thermal Shock of $(\text{NH}_4)_2\text{MoS}_3$ Leads to Ultrafast Synthesis of Porous Ensembles of $\text{MoS}_2$ Nanocrystals for High Gain Photodetectors. <i>ACS Applied Materials &amp; Interfaces</i> , 2018, 10, 38193-38200.	8.0	5
35	Deep Level and Near-Band-Edge Recombination in Semiconducting Antiperovskite $\text{Hg}_3\text{Se}_2\text{I}_2$ Single Crystals. <i>Advanced Optical Materials</i> , 2018, 6, 1800328.	7.3	2
36	Resolving the Energy of $\beta$ -Ray Photons with $\text{MAPbI}_3$ Single Crystals. <i>ACS Photonics</i> , 2018, 5, 4132-4138.	6.6	100

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37	Conversion of Single Crystal (NH <sub>4</sub> ) <sub>2</sub> MoS <sub>3</sub> ·H <sub>2</sub> O to Isomorphic Pseudocrystals of MoS <sub>2</sub> Nanoparticles. Chemistry of Materials, 2018, 30, 3847-3853.	6.7	14
38	Cs <sub>2</sub> PbCl <sub>2</sub> , All-Inorganic Two-Dimensional Ruddlesden-Popper Mixed Halide Perovskite with Optoelectronic Response. Journal of the American Chemical Society, 2018, 140, 11085-11090.	13.7	167
39	∓-Particle Detection and Charge Transport Characteristics in the A <sub>3</sub> M <sub>2</sub> I <sub>9</sub> Defect Perovskites (A = Cs, Rb; M = Bi, Sb). ACS Photonics, 2018, 5, 3748-3762.	6.6	88
40	Defect Antiperovskite Compounds Hg <sub>3</sub> Q <sub>2</sub> I <sub>2</sub> (Q = S, Se, and Te) for Room-Temperature Hard Radiation Detection. Journal of the American Chemical Society, 2017, 139, 7939-7951.	13.7	45
41	TlSn <sub>2</sub> I <sub>5</sub> , a Robust Halide Antiperovskite Semiconductor for <sup>137</sup> I-Ray Detection at Room Temperature. ACS Photonics, 2017, 4, 1805-1813.	6.6	33
42	Improvement of the THz response of Zn <sub>1-x</sub> Mn <sub>x</sub> Te bulk crystals grown by a temperature gradient solution method. CrystEngComm, 2017, 19, 3051-3057.	2.6	2
43	Electronic defects in the halide antiperovskite semiconductor $\text{HgI}_2$ . Physical Review B, 2017, 96, ...	3.2	3
44	Improved Crystal Growth of Tl <sub>6</sub> SeI <sub>4</sub> for <sup>137</sup> I-Ray Detection Material by Oxide Impurity Removal. Crystal Growth and Design, 2017, 17, 6096-6104.	3.0	6
45	Refined Synthesis and Crystal Growth of Pb <sub>2</sub> P <sub>2</sub> Se <sub>6</sub> for Hard Radiation Detectors. Crystal Growth and Design, 2016, 16, 5100-5109.	3.0	12
46	Te inclusion-induced electrical field perturbation in CdZnTe single crystals revealed by Kelvin probe force microscopy. Micron, 2016, 88, 48-53.	2.2	6
47	Calculation of the High-Temperature Point Defects Structure in Te-Rich CdTe. Journal of Electronic Materials, 2016, 45, 4747-4754.	2.2	1
48	Comparison of In doped and In, Pb co-doped Cd <sub>0.9</sub> Zn <sub>0.1</sub> Te. Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment, 2015, 790, 10-13.	1.6	4
49	Interplay mechanism between secondary phase particles and extended dislocations in CdZnTe crystals. CrystEngComm, 2015, 17, 8639-8644.	2.6	10
50	Characterization of CdZnTe co-doped with indium and lead. Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment, 2015, 770, 48-51.	1.6	5
51	Migration of Te inclusions in CdZnTe single crystals under the temperature gradient annealing. Journal of Crystal Growth, 2014, 402, 15-21.	1.5	16
52	TEM study on HgIn <sub>2</sub> Te <sub>4</sub> precipitates in Hg <sub>3</sub> In <sub>2</sub> Te <sub>6</sub> crystals grown by the Bridgman method. CrystEngComm, 2014, 16, 7660-7666.	2.6	2
53	HRTEM study on the ordered phases in Hg <sub>3</sub> In <sub>2</sub> Te <sub>6</sub> crystals grown by Bridgman method. CrystEngComm, 2014, 16, 5073-5079.	2.6	4
54	Dislocation-mediated coupling mechanism between the microstructural defects and Te inclusions in CdZnTe single crystals. Scripta Materialia, 2014, 82, 17-20.	5.2	18

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55	Research into the electrical property variation of undoped CdTe and ZnTe crystals grown under Te-rich conditions. <i>Journal of Alloys and Compounds</i> , 2014, 612, 392-397.	5.5	17
56	Correlation of dislocations and Te inclusions in detector-grade CdZnTe crystals grown by MVB method. , 2012, , .		0
57	Investigation of Te inclusion induced glides and the corresponding dislocations in CdZnTe crystal. <i>CrystEngComm</i> , 2012, 14, 417-420.	2.6	20
58	Study of Te aggregation at the initial growth stage of CdZnTe films deposited by CSS. <i>Applied Physics A: Materials Science and Processing</i> , 2012, 108, 447-450.	2.3	6
59	Matrix-controlled morphology evolution of Te inclusions in CdZnTe single crystal. <i>Scripta Materialia</i> , 2012, 67, 5-8.	5.2	26
60	Morphology evolution of micron-scale secondary phases in CdZnTe crystals grown by vertical Bridgman method. <i>Journal of Alloys and Compounds</i> , 2011, 509, 2338-2342.	5.5	15
61	Characterization of detector-grade CdZnTe:Al crystals obtained by annealing. <i>Journal of Crystal Growth</i> , 2011, 324, 22-25.	1.5	5